

MM74HC125, MM74HC126

3-STATE Quad Buffers

Features

- Typical propagation delay: 13ns
- Wide operating voltage range: 2V–6V
- Low input current: 1μA maximum
- Low quiescent current: 80μA maximum (74HC)
- Fanout of 15 LS-TTL loads

General Description

The MM74HC125 and MM74HC126 are general purpose 3-STATE high speed non-inverting buffers utilizing advanced silicon-gate CMOS technology. They have high drive current outputs which enable high speed operation even when driving large bus capacitances. These circuits possess the low power dissipation of CMOS circuitry, yet have speeds comparable to low power Schottky TTL circuits. Both circuits are capable of driving up to 15 low power Schottky inputs.

The MM74HC125 require the 3-STATE control input C to be taken high to put the output into the high impedance condition, whereas the MM74HC126 require the control input to be low to put the output into high impedance.

All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Ordering Information

Order Number	Package Number	Package Description
MM74HC125M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC125SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC125N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HC126M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC126SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC126MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC126N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

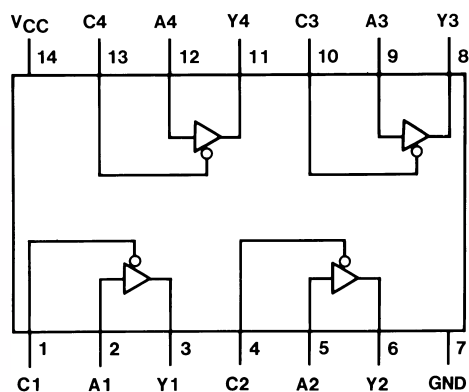
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.



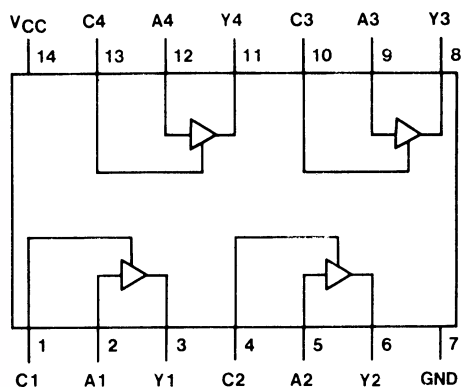
All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagrams

Pin Assignments for DIP, SOIC, SOP and TSSOP



Top View (MM74HC125)



Top View (MM74HC126)

Truth Tables

Inputs		Output
A	C	Y
H	L	H
L	L	L
X	H	Z

MM74HC125

Inputs		Output
A	C	Y
H	H	H
L	H	L
X	L	Z

MM74HC126

Absolute Maximum Ratings⁽¹⁾

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V_{CC}	Supply Voltage	−0.5 to +7.0V
V_{IN}	DC Input Voltage	−1.5 to $V_{CC}+1.5V$
V_{OUT}	DC Output Voltage	−0.5 to $V_{CC}+0.5V$
I_{IK}, I_{OK}	Clamp Diode Current	±20mA
I_{OUT}	DC Output Current, per pin	35mA
I_{CC}	DC V_{CC} or GND Current, per pin	±70mA
T_{STG}	Storage Temperature Range	−65°C to +150°C
P_D	Power Dissipation Note 2	600mW
	S.O. Package only	500mW
T_L	Lead Temperature (Soldering 10 seconds)	260°C

Notes:

1. Unless otherwise specified all voltages are referenced to ground.
2. Power Dissipation temperature derating — plastic “N” package: −12mW/°C from 65°C to 85°C.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
V_{CC}	Supply Voltage	2	6	V
V_{IN}, V_{OUT}	DC Input or Output Voltage	0	V_{CC}	V
T_A	Operating Temperature Range	−40	+85	°C
t_r, t_f	Input Rise or Fall Times $V_{CC} = 2.0V$		1000	ns
	$V_{CC} = 4.5V$		500	ns
	$V_{CC} = 6.0V$		400	ns

DC Electrical Characteristics⁽³⁾

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25°C	T _A = -40°C to 85°C	T _A = -40°C to 125°C	Units	
				Typ.	Guaranteed Limits			
V _{IH}	Minimum HIGH Level Input Voltage		2.0		1.5	1.5	V	
			4.5		3.15	3.15		
			6.0		4.2	4.2		
V _{IL}	Maximum LOW Level Input Voltage		2.0		0.5	0.5	V	
			4.5		1.35	1.35		
			6.0		1.8	1.8		
V _{OH}	Minimum HIGH Level Output Voltage	V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 20μA	2.0	2.0	1.9	1.9	V	
			4.5	4.5	4.4	4.4		
			6.0	6.0	5.9	5.9		
		V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 6.0mA	4.5	4.2	3.98	3.84		
		V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 7.8mA	6.0	5.7	5.48	5.34		
V _{OL}	Maximum LOW Level Output Voltage	V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 20μA	2.0	0	0.1	0.1	V	
			4.5	0	0.1	0.1		
			6.0	0	0.1	0.1		
		V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 6.0mA	4.5	0.2	0.26	0.33		
		V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 7.8mA	6.0	0.2	0.26	0.33		
I _{OZ}	Maximum 3-STATE Output Leakage Current	V _{IN} = V _{IH} or V _{IL} , V _{OUT} = V _{CC} or GND, C _n = Disabled	6.0		±0.5	±5	±10	μA
I _{IN}	Maximum Input Current	V _{IN} = V _{CC} or GND	6.0		±0.1	±1.0	±1.0	μA
I _{CC}	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND, I _{OUT} = 0μA	6.0		8.0	80	160	μA

Note:

3. For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC}=5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics $V_{CC} = 5V$, $T_A = 25^\circ C$, $C_L = 45pF$, $t_r = t_f = 6ns$

Symbol	Parameter	Conditions	Typ.	Guaranteed Limit	Units
t_{PHL} , t_{PLH}	Maximum Propagation Delay Time		13	18	ns
t_{PZH}	Maximum Output Enable Time to HIGH Level	$R_L = 1k\Omega$	13	25	ns
t_{PHZ}	Maximum Output Disable Time from HIGH Level	$R_L = 1k\Omega$, $C_L = 5pF$	17	25	ns
t_{PZL}	Maximum Output Enable Time to LOW Level	$R_L = 1k\Omega$	18	25	ns
t_{PLZ}	Maximum Output Disable Time from LOW Level	$R_L = 1k\Omega$, $C_L = 5pF$	13	25	ns

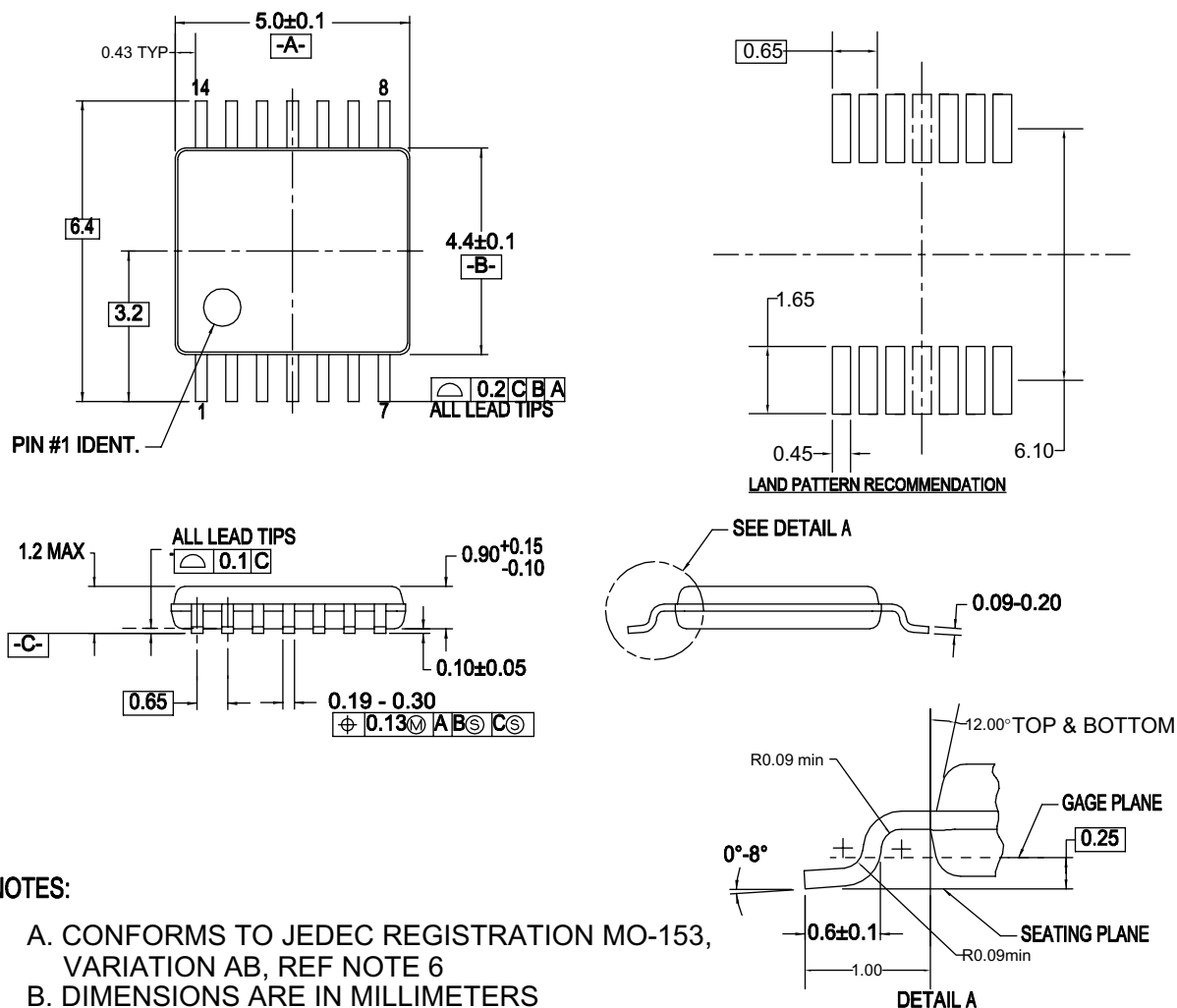
AC Electrical Characteristics $V_{CC} = 2.0V$ to $6.0V$, $C_L = 50pF$, $t_r = t_f = 6ns$ (unless otherwise specified)

Symbol	Parameter	V _{CC} (V)	Conditions	T _A = 25°C		T _A = −40°C to 85°C	T _A = −40°C to 125°C	Units
				Typ.	Guaranteed Limits			
t _{PHL} , t _{PLH}	Maximum Propagation Delay Time	2.0		40	100	125	150	ns
		4.5		14	20	25	30	
		6.0		12	17	21	25	
t _{PLH} , t _{PHL}	Maximum Propagation Delay Time	2.0	C _L = 150pF	35	130	163	195	ns
		4.5		14	26	33	39	
		6.0		12	22	28	39	
t _{PZH} , t _{PZL}	Maximum Output Enable Time	2.0	R _L = 1kΩ	25	125	156	188	ns
		4.5		14	25	31	38	
		6.0		12	21	26	31	
t _{PHZ} , t _{PLZ}	Maximum Output Disable Time	2.0	R _L = 1kΩ	25	125	156	188	ns
		4.5		14	25	31	38	
		6.0		12	21	26	31	
t _{PZL} , t _{PZH}	Maximum Output Enable Time	2.0	C _L = 150pF, R _L = 1kΩ	35	140	175	210	ns
		4.5		15	28	35	42	
		6.0		13	24	30	36	
t _{TLH} , t _{THL}	Maximum Output Rise and Fall Time	2.0V	C _L = 50pF	30	60	75	90	ns
		4.5V		7	12	15	18	
		6.0V		6	10	13	15	
C _{IN}	Input Capacitance			5	10	10	10	pF
C _{OUT}	Output Capacitance Outputs			15	20	20	20	pF
C _{PD}	Power Dissipation Capacitance (per gate) ⁽⁴⁾		Enabled	45				pF
			Disabled	6				

Note:

4. C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

Physical Dimensions (Continued)



NOTES:

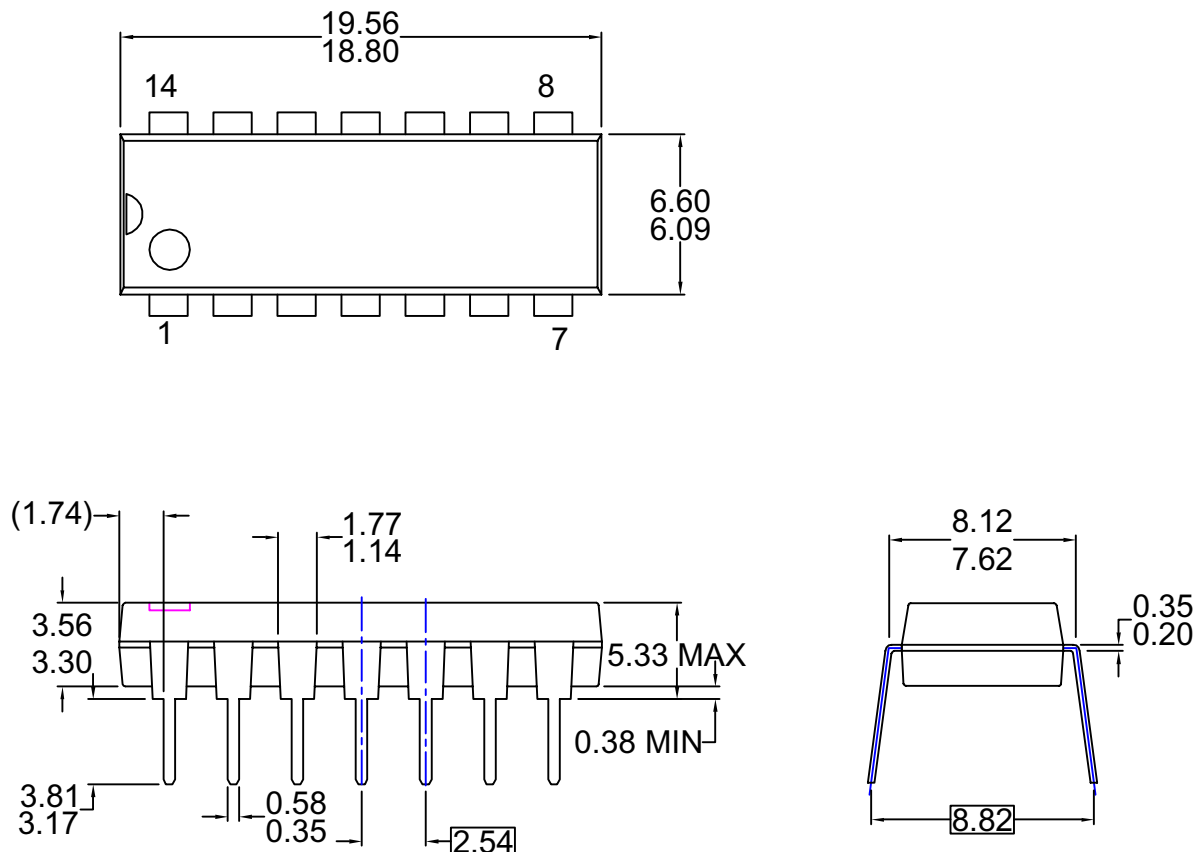
- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6
- B. DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS
- D. DIMENSIONING AND TOLERANCES PER ANSI Y14.5M, 1982
- E. LANDPATTERN STANDARD: SOP65P640X110-14M
- F. DRAWING FILE NAME: MTC14REV6

Figure 3. 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

<http://www.fairchildsemi.com/packaging/>

Physical Dimensions (Continued)**NOTES: UNLESS OTHERWISE SPECIFIED**

THIS PACKAGE CONFORMS TO

A) JEDEC MS-001 VARIATION BA

B) ALL DIMENSIONS ARE IN MILLIMETERS.

C) DIMENSIONS ARE EXCLUSIVE OF BURRS,
MOLD FLASH, AND TIE BAR EXTRUSIONS.D) DIMENSIONS AND TOLERANCES PER
ASME Y14.5-1994

E) DRAWING FILE NAME: MKT-N14AREV7

Figure 4. 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

<http://www.fairchildsemi.com/packaging/>



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

ACEx®	FPS™	PDP-SPM™	SupreMOS™
Build it Now™	FRFET®	Power220®	SyncFET™
CorePLUS™	Global Power Resource™	POWEREDGE®	SYSTEM GENERAL®
CROSSVOLT™	Green FPS™	Power-SPM™	The Power Franchise®
CTL™	Green FPS™ e-Series™	PowerTrench®	the power franchise
Current Transfer Logic™	GTO™	Programmable Active Droop™	TinyBoost™
EcoSPARK®	i-Lo™	QFET®	TinyBuck™
EZSWITCH™ *	IntelliMAX™	QS™	TinyLogic®
 ™	ISOPLANAR™	QT Optoelectronics™	TINYOPTO™
 ™	MegaBuck™	Quiet Series™	TinyPower™
Fairchild®	MICROCOUPLER™	RapidConfigure™	TinyPWM™
Fairchild Semiconductor®	MicroFET™	SMART START™	TinyWire™
FACT Quiet Series™	MicroPak™	SPM®	µSerDes™
FACT®	MillerDrive™	STEALTH™	UHC®
FAST®	Motion-SPM™	SuperFET™	Ultra FRFET™
FastvCore™	OPTOLOGIC®	SuperSOT™.3	UniFET™
FlashWriter® *	OPTOPLANAR®	SuperSOT™.6	VCX™
		SuperSOT™.8	

* EZSWITCH™ and FlashWriter® are trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild Semiconductor. The datasheet is printed for reference information only.

Rev. I33